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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/838,483	04/19/2001	Louise C. Sengupta	283014-00018-1	8925
27512	7590 11/26/2002			
WILLIAM J. TUCKER			EXAMINER	
8650 SOUTH DALLAS, TX	WESTERN BLVD. #2825 75206		HAM, SEUNGSOOK	
			ART UNIT	PAPER NUMBER
			2817	
			DATE MAILED: 11/26/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

			<i>!</i> *				
	Application No.	pplicant(s)					
	09/838,483	SENGUPTA ET AL.					
Office Action Summary	Examiner	Art Unit					
	Seungsook Ham	2817					
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the	correspondence address	s				
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1: after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period v - Failure to reply within the set or extended period for reply will, by statute - Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). Status	36(a). In no event, however, may a reply be to within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDON	timely filed ays will be considered timely. m the mailing date of this commun IED (35 U.S.C. § 133).	nication.				
1)⊠ Responsive to communication(s) filed on <u>15 (</u>	October 2002						
	is action is non-final.						
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Disposition of Claims							
4)⊠ Claim(s) <u>1,2 and 4-18</u> is/are pending in the ap	•						
<u> </u>	4a) Of the above claim(s) is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.							
6)⊠ Claim(s) <u>1, 2 and 4-18</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/or Application Papers	r election requirement.						
9)☐ The specification is objected to by the Examine							
10) The drawing(s) filed on is/are: a) □ accept		aminor					
Applicant may not request that any objection to the	•	•					
11) The proposed drawing correction filed on	•	• •					
If approved, corrected drawings are required in rep							
12) The oath or declaration is objected to by the Ex	•						
Priority under 35 U.S.C. §§ 119 and 120							
13) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a)-(d) or (f).					
a) ☐ All b) ☐ Some * c) ☐ None of:							
1. Certified copies of the priority documents	s have been received.						
2. Certified copies of the priority documents	s have been received in Applica	tion No					
Copies of the certified copies of the prior application from the International But See the attached detailed Office action for a list	reau (PCT Rule 17.2(a)).	·	е				
14) ☐ Acknowledgment is made of a claim for domestic	c priority under 35 U.S.C. § 119	(e) (to a provisional appl	lication).				
 a) The translation of the foreign language pro 15) Acknowledgment is made of a claim for domesti 							
Attachment(s)							
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal	ry (PTO-413) Paper No(s) I Patent Application (PTO-152					

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DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1, 4, 5 and 13-18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Vandik et al. ("Ferroelectric Tuning of Planar and Bulk Microwave Devices").

Vandik et al. (fig. 14) discloses a tunable finline phase shifter comprising: a waveguide (p. 333, section 6), a finline substrate, a tunable dielectric layer (ferroelectric material) and first and second conductors positioned on the tunable dielectric layer and separated to form a gap s. Vandik et al. is silent as to the specific range for the gap s. However, Vandik et al. teaches that the gap/slot provides capacitance (see page 333-

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34, sec. 6.1) which is the same concept as the applicant's invention (see spec. page 5, lines 8-11). Moreover, the applicant does not provide any criticality of such range in the disclosure.

Therefore, it would have been obvious to one of ordinary skill in the art to provide the gap having a minimum width ranging from 2 micron to 50 micron in the device of Vandik et al. to provide a desired capacitance coupling since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or workable ranges involves only routine skill in the art. *In re Aller*, 105 USPQ 233 (CCPA 1955), also *In re Boesch*, 205 USPQ 215 (CCPA 1980).

Regarding claim 4, it is inherent that a voltage source is applied to the first and second conductor to tune the phase shift (p. 334, section 6.2)

Regarding claim 13, Vandik et al. teaches the ferroelectric material can be composed of BSTO (p. 327, section 3.2).

Regarding to claim 5, forming the second conductor as RF ground is an obvious modification since one conductor should be grounded in order to function as a phase shifter using a tunable dielectric layer.

Regarding claims 14-18, it would have been obvious to use the materials recited in these claims in the device of Vandik et al. since they are well known ferroelectric material.

Claims 2 and 6 are rejected under 35 U.S.C. 103(a) as being unpatentable over Vandik et al. ("Ferroelectric Tuning of Planar and Bulk Microwave Devices") in view of Conti (US '654).

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Regarding claim 2, Vandik et al. does not show the gap having exponentially tapered portions adjacent to the first and the second ends. However, it should be noted that Vandik et al. shows the gap having stepped portions at the ends (see fig. 15) for impedance matching. Thus, it would have been obvious to one of ordinary skill in the art to provide the gap having exponentially tapered portions at the ends in the device of Vandik et al. for impedance matching since such design technique is well known in the art.

Regarding to claim 6, providing an RF choke in a phase shifter is well known in the art as shown by Conti (fig. 5, RF choke patches 82). Thus, it would have been obvious to provide an RF choke in the device of Vandik et al. to suppress high RF signals.

Claims 7-12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Vandik et al. ("Ferroelectric Tuning of Planar and Bulk Microwave Devices") in view of Bates (EP '393).

Vandik et al. does not show a first conductive plate/conductor being insulated from the waveguide and a second conductive plate/conductor being electrically connected to the waveguide. However, such finline structure is well known in the art. Bates (fig. 2) discloses a finline structure having a first conductive plate/conductor 4 being insulated from the waveguide 8, 9 and a second conductive plate/conductor 5 being electrically connected to the waveguide. Therefore, it would have been obvious to one of ordinary skill in the art to provide a first conductive plate/conductor being insulated from the waveguide and a second conductive plate/conductor being

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electrically connected to the waveguide in the device of Vandik et al. to couple the first conductive plate/conductor to the waveguide at microwave frequencies but isolated at lower frequencies (p. 4, lines 9-25).

Regarding claims 8, 9, 11 and 12, it would have been obvious to provide exponentially taped gap between the first and second conductive plates in the device of Vandik et al. for impedance matching as shown by Bates (see fig. 1).

Response to Arguments

Applicant's arguments filed on 10/15/02 have been fully considered but they are not persuasive.

In response to the applicant's argument that Vandik et al. does not show "the first and second conductors being separated to form a gap having a minimum width ranging from 2 micron to 50 micron", the examiner respectfully disagrees.

It should be noted that applicant's disclosure merely states "a gap 54 between two generally parallel edges of the metalized conductors with the width of the gap ranging from about 2 to about 50 μm to form a capacitor." (See spec. page 5, lines 8-10). There are no other place in the disclosure describe about the criticality of such range. Vandik et al. (pp. 333-34, section 6.1) discloses the identical device as the applicant's claimed invention except the range of the gap s. However, Vandik et al. teaches that the gap s provide capacitance (see fig. 14, equivalent circuit) and also discloses the length/width of the slot is dependent on capacitance value (see equation 20). Therefore, it is the examiner's position that it would have been obvious to one of ordinary skill in the art would obtain such workable range since it requires only routine

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skill in the art. See, *In re Aller*, 105 USPQ 233 (CCPA 1955), also *In re Boesch*, 205 USPQ 215 (CCPA 1980).

Applicant's arguments with respect to claims 1, 2 and 4-18 have been considered but are most in view of the new ground(s) of rejection.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Seungsook Ham whose telephone number is (703) 308-4090. The examiner can normally be reached on Monday - Thursday from 8:00 A.M. to 5:00 P.M..

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert J. Pascal can be reached on (703)308-4909. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7724 for regular communications and (703) 308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703)308-0956.

Seungsook Ham Primary Examiner Art Unit 2817

sh November 21, 2002